查询SK510-B供应商

Chip Schottky Barrier Diodes

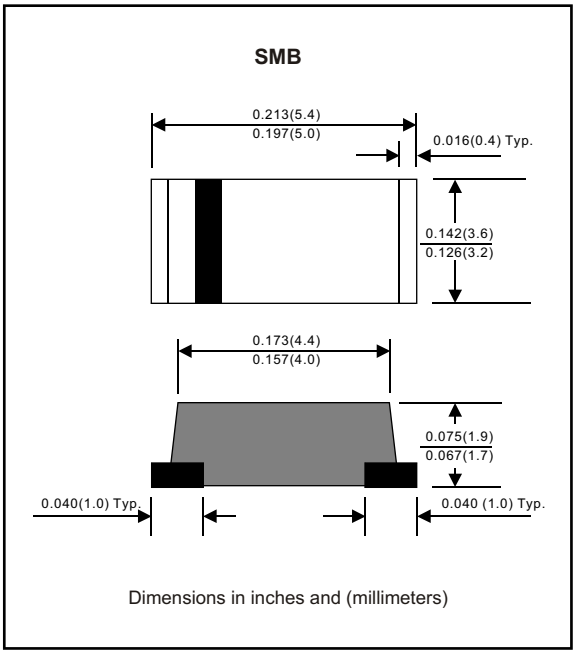
Formosa MS

SK52-B THRU SK510-B

Silicon epitaxial planer type

Features

- Plastic package has Underwriters Laboratory Flammability Classification 94V-O Utilizing Flame Retardant Epoxy Molding Compound.
- For surface mounted applications.
- Exceeds environmental standards of MIL-S-19500 / 228
- Low leakage current



Dimensions in inches and (millimeters)

Mechanical data

Case : Molded plastic, JEDEC DO-214AA
Terminals : Solder plated, solderable per MIL-STD-750, Method 2026
Polarity : Indicated by cathode band
Mounting Position : Any
Weight : 0.00878 ounce, 0.293 gram

MAXIMUM RATINGS *(AT T_A=25°C unless otherwise noted)*

PARAMETER	CONDITIONS	Symbol	MIN.	TYP.	MAX.	UNIT
Forward rectified current	See Fig.1	I_O			5.0	A
Forward surge current	8.3ms single half sine-wave superimposed on rate load (JEDEC methode)	I_{FSM}			150	A
Reverse current	V_R = V_{RRM} T_A = 25°C	I_R			1	mA
	V_R = V_{RRM} T_A = 125°C				50	mA
Thermal resistance	Junction to lead	R_{JL}		12		°C / W
Diode junction capacitance	f=1MHz and applied 4vDC reverse voltage	C_J		380		pF
Storage temperature		T_{STG}	-55		+150	°C

SYMBOLS	MARKING CODE	V_{RRM} *1 (V)	V_{RMS} *2 (V)	V_R *3 (V)	V_F *4 (V)	Operating temperature (°C)
SK52-B	SS52	20	14	20	0.50	-55 to +125
SK53-B	SS53	30	21	30		
SK54-B	SS54	40	28	40		
SK55-B	SS55	50	35	50	0.70	-55 to +150
SK56-B	SS56	60	42	60		
SK58-B	SS58	80	56	80	0.85	
SK510-B	S510	100	70	100		

*1 Repetitive peak reverse voltage
*2 RMS voltage
*3 Continuous reverse voltage
*4 Maximum forward voltage

RATING AND CHARACTERISTIC CURVES (SK52B THRU SK510B)

FIG.1-TYPICAL FORWARD CURRENT DERATING CURVE

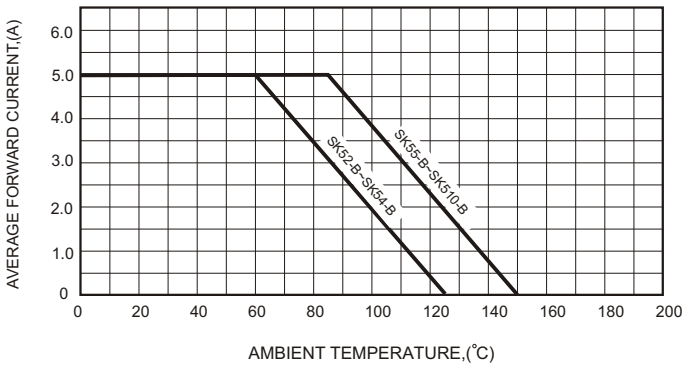


FIG.2-TYPICAL FORWARD CHARACTERISTICS

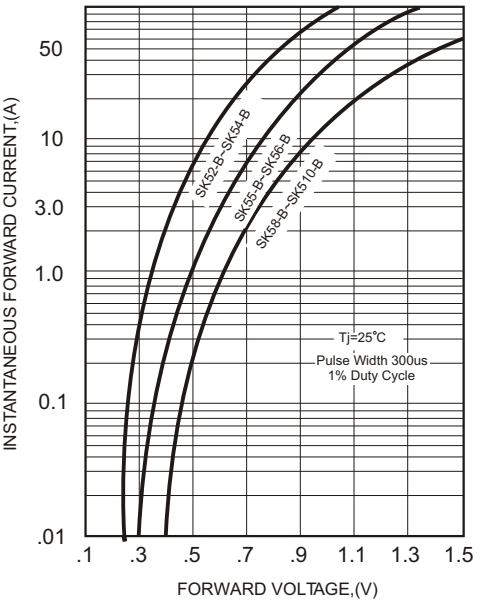


FIG.3-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

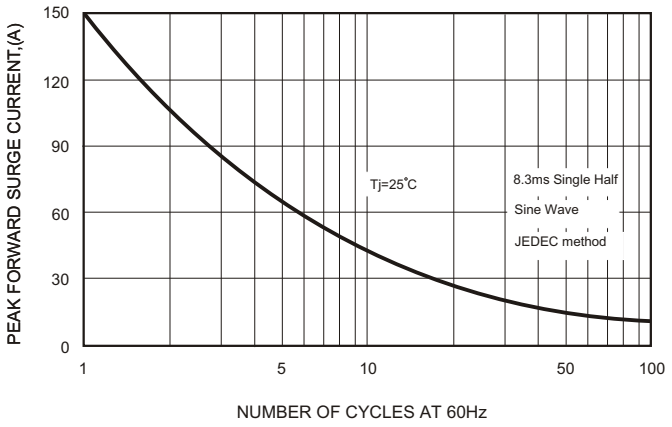


FIG.4-TYPICAL JUNCTION CAPACITANCE

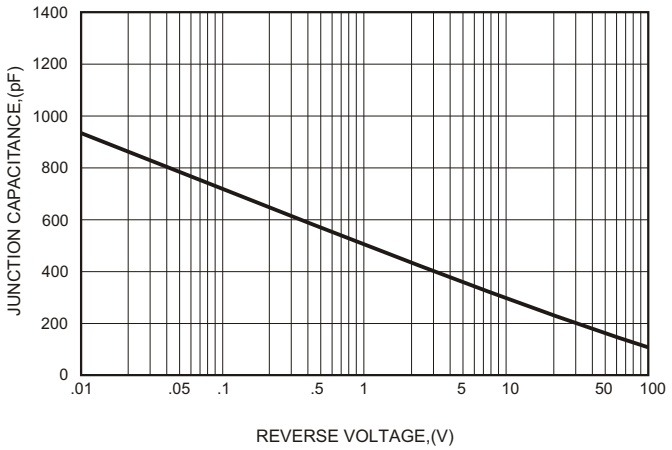


FIG.5 - TYPICAL REVERSE CHARACTERISTICS